









<span id="page-0-0"></span>**IT** TEXAS **INSTRUMENTS** 

#### **[TPS62870](https://www.ti.com.cn/product/cn/tps62870?qgpn=tps62870), [TPS62871,](https://www.ti.com.cn/product/cn/tps62871?qgpn=tps62871) [TPS62872](https://www.ti.com.cn/product/cn/tps62872?qgpn=tps62872), [TPS62873](https://www.ti.com.cn/product/cn/tps62873?qgpn=tps62873)** [ZHCSNZ3B](https://www.ti.com.cn/cn/lit/pdf/ZHCSNZ3) – JANUARY 2023 – REVISED MAY 2024

# **TPS6287x** 具有快速瞬态响应功能的 **2.7V** 至 **6V** 输入 **6A**、**9A**、**12A**、**15A** 可堆叠同步降压转换器

## **1** 特性

- [功能安全型](http://www.ti.com/technologies/functional-safety/overview.html#commitment)
- [可提供用于功能安全系统设计的文档](https://www.ti.com/lit/pdf/SFFS792)
- 2.7V 至 6V 输入电压范围
- 6A、9A、12A 和 15A 系列引脚对引脚兼容器件
- 四个输出电压范围:
	- 0.4V 至 0.71875V(步长为 1.25mV)
	- 0.4V 至 1.0375V(步长为 2.5mV)
	- 0.4V 至 1.675V(步长为 5mV)
	- 0.8V 至 3.35V(步长为 10mV)
- 输出电压精度为 ±1%
- 7mΩ 和 4.5mΩ 内部功率 MOSFET
- 可调节外部补偿
- 电阻可选启动输出电压
- 电阻可选开关频率
- 节电或强制 PWM 操作
- 与 I2C 兼容的接口频率高达 1MHz
- 差分遥感
- 旨在提高输出电流能力的可选堆叠操作
- 热警告和热关断
- 精密使能输入
- 有源输出放电
- 可选展频时钟
- 具有窗口比较器的电源正常输出
- 采用具有可湿性侧面的 2.55mm × 3.55mm × 1mm VQFN 封装
- 结温范围为 40°C 至 125°C, T」

## **2** 应用

- [光纤网络](https://www.ti.com/solution/optical-module)
- [存储](https://www.ti.com/applications/personal-electronics/data-storage/overview.html)
- FPGA、ASIC [和数字内核电源](https://www.ti.com/design-resources/design-tools-simulation/processor-fpga-power/overview.html)
- DDR 存储器电源

## **3** 说明

TPS6287x 是具有远程差分检测功能的引脚对引脚 6A、9A、12A 和 15A 同步直流/直流降压转换器系 列。对于每个电流额定值,都有适用的具有 I<sup>2</sup>C 接口且 功能全面的器件型号,以及不具有 I2C 接口且功能有限 的器件型号。所有器件都具有高效率且易于使用。低阻 电源开关可在高温环境下支持高达 15A 的持续输出电 流。

这些器件可在堆叠模式下运行,以提供更高的输出电流 或将功耗分散到多个器件上。

TPS6287x 系列实现了增强型 DCS 控制方案,该方案 支持具有固定频率操作的快速瞬变。器件可以在省电模 式下运行以充分提高效率,也可以在强制 PWM 模式下 运行以实现出色瞬态性能和超低输出电压纹波。

可选的远程检测功能可充分提升负载点的电压调节,并 且该器件在所有运行条件下均可实现优于 ±1% 的直流 电压精度。

器件信息

偷工旧心			
器件型号(2)	电流额定值	封装(1)	
TPS62870	6A		
TPS62871	9Α	RXS (VQFN-	
TPS62872	12A	FCRLF, 16)	
TPS62873	15A		

(1) 如需了解更多信息,请参阅节 [13](#page-52-0)。

(2) 请参阅*[器件选项](#page-2-0)表*。



**TPS6287x** 简化原理图





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# **4** 说明(续)

通过 FSEL 引脚实现电阻可选开关频率。开关频率可设置为 1.5MHz、2.25MHz、2.5MHz 或 3.0MHz, 也可与频 率范围相同的外部时钟同步。

I<sup>2</sup>C 兼容接口提供多种控制、监控和警告功能, 例如电压监控和温度相关警告。通过 I<sup>2</sup>C 兼容接口可快速调整输出 电压,使负载功耗适应应用性能需求。通过 VSEL 引脚,默认启动电压可实现电阻可选。

## **5 Device Options**



(1) The I<sup>2</sup>C address is linked to the selected start-up voltage. The user cannot select the start-up voltage and I<sup>2</sup>C address independently.

(2) The user can use the VSEL pin to select which of the four start-up voltages the device uses. For more information, see  $*$  [8-5](#page-21-0) and  $*$ [8-10.](#page-31-0)

Unless otherwise noted, device variants without I<sup>2</sup>C operate with the same default settings as device variants with  $I^2C$ .



## <span id="page-3-0"></span>**6 Pin Configuration and Functions**





## 表 **6-1. Pin Functions**



<span id="page-4-0"></span>

## 表 **6-1. Pin Functions** (续)



(1)  $I = input$ ,  $O = output$ ,  $P = power$ ,  $GND = ground$ 

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## <span id="page-5-0"></span>**7 Specifications**

## **7.1 Absolute Maximum Ratings**

over operating temperature range (unless otherwise noted) $(1)$ 



(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

(2) All voltage values are with respect to the GND pin.

(3) While switching.

(4) The voltage at the pin can exceed the 6.5 V absolute max condition for a short period of time, but must remain less than 8 V. VIN at 8 V for a 100ms duration is equivalent to approximately 8 hours of aging for the device at room temperature.

## **7.2 ESD Ratings\_Catalog**



(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

## **7.3 Recommended Operating Conditions**

Over operating temperature range (unless otherwise noted)



<span id="page-6-0"></span>

## **7.3 Recommended Operating Conditions** (续)

Over operating temperature range (unless otherwise noted)



(1) Whichever value is lower.

(2) *Effective* capacitance.

(3) The maximum recommended output capacitance depends on the specific operating conditions of an application. Output capacitance values up to a few millifarad are typically possible, however.

## **7.4 Thermal Information**



(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](http://www.ti.com/lit/SPRA953) application report.

## **7.5 Electrical Characteristics**

over operating junction temperature (T $_{\rm J}$  =  $\,$  - 40 °C to 125 °C) and V $_{\rm IN}$  = 2.7 V to 6 V. Typical values at V $_{\rm IN}$  = 3.3 V and T $_{\rm J}$  = 25 °C (unless otherwise noted).



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## **7.5 Electrical Characteristics** (续)

over operating junction temperature (T」=  $-$  40 °C to 125 °C) and V<sub>IN</sub> = 2.7 V to 6 V. Typical values at V<sub>IN</sub> = 3.3 V and T」 = 25 °C (unless otherwise noted).



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## **7.5 Electrical Characteristics** (续)

over operating junction temperature (T」=  $-$  40 °C to 125 °C) and V<sub>IN</sub> = 2.7 V to 6 V. Typical values at V<sub>IN</sub> = 3.3 V and T」 = 25 °C (unless otherwise noted).





## <span id="page-9-0"></span>**7.6 I <sup>2</sup>C Interface Timing Characteristics**



## **7.7 Timing Requirements**



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## <span id="page-11-0"></span>**7.8 Typical Characteristics**



<span id="page-12-0"></span>

## **8 Detailed Description**

## **8.1 Overview**

The TPS6287x devices are synchronous step-down (buck) DC/DC converters. These devices use an enhanced DCS control topology to achieve fast transient response while switching with a fixed frequency. Together, with the low output voltage ripple, high DC accuracy, and differential remote sensing, these devices are ideal for supplying the cores of modern high-performance processors.

The family of devices includes 6A, 9A, 12A, and 15A devices. To further increase the output current capability, the user can combine multiple devices in a "stack". For example, a stack of two TPS62873 devices have a current capability of 30A. Each device of a stack must have the same current rating to avoid that one device enters current limit too early.

For each current rating, there are full-featured devices with an I<sup>2</sup>C interface and limited-featured devices without an I2C interface (see the *[Device Options](#page-2-0)*). The user can use a device variant without I2C in exactly the same way as a device variant with  $I^2C$ , except that:

- The user must connect the unused SCL and SDA pins to GND.
- The user must be aware of the (fixed) factory settings for parameters and functions that are programmable in the I2C device variants.



## <span id="page-13-0"></span>**8.2 Functional Block Diagram**



<span id="page-14-0"></span>

## **8.3 Feature Description**

## *8.3.1 Fixed-Frequency DCS Control Topology*

图 8-1 shows a simplified block diagram of the fixed-frequency enhanced DCS control topology used in the TPS6287x devices. This topology is comprised of an inner emulated current loop, a middle direct feedback loop, and an outer voltage-regulating loop.



## 图 **8-1. Fixed-Frequency DCS Control Topology (Simplified)**

## *8.3.2 Forced PWM and Power Save Modes*

The device can control the inductor current in three different ways to regulate the output:

- Pulse-width modulation with continuous inductor current (PWM-CCM)
- Pulse-width modulation with discontinuous inductor current (PWM-DCM)
- Pulse-frequency modulation with discontinuous inductor current and pulse skipping (PFM-DCM)

During PWM-CCM operation, the device switches at a constant frequency and the inductor current is continuous (see  $\boxtimes$  [8-2](#page-15-0)). PWM operation achieves the lowest output voltage ripple and the best transient performance.



<span id="page-15-0"></span>

图 **8-2. Continuous Conduction Mode (PWM-CCM) Current Waveform**

During PWM-DCM operation, the device switches at a constant frequency and the inductor current is discontinuous (see  $\boxtimes$  8-3). In this mode, the device controls the peak inductor current to maintain the selected switching frequency while still being able to regulate the output.



图 **8-3. Discontinuous Conduction Mode (PWM-DCM) Current Waveform**

During PFM-DCM operation, the device keeps the peak inductor current constant (at a level corresponding to the minimum on time of the converter) and skips pulses to regulate the output (see  $\boxtimes$  8-4). The switching pulses that occur during PFM-DCM operation are synchronized to the internal clock.





For very small output voltages, an absolute minimum on time of approximately 50 ns reduces the switching frequency from the set value.  $\& 7-5$  shows the maximum switching frequency with 3.3V and 5.5V supplies.

Use 方程式 1 to calculate the output current threshold at which the device enters PFM-DCM.

$$
I_{\text{OUT(PFM)}} = \frac{(V_{\text{IN}} - V_{\text{OUT}})}{2L} t_{\text{ON}}^2 \left(\frac{V_{\text{IN}}}{V_{\text{OUT}}}\right) f_{\text{sw}}
$$
(1)

 $\boxtimes$  [8-5](#page-16-0) shows how this threshold typically varies with V<sub>IN</sub> and V<sub>OUT</sub> for a switching frequency of 2.25MHz.

<span id="page-16-0"></span>



图 **8-5. Output Current PFM-DCM Entry Threshold**

The user can configure the device to use either forced PWM (FPWM) mode or power save mode (PSM):

- In forced PWM mode, the device uses PWM-CCM at all times.
- In power save mode, the device uses PWM-CCM at medium and high loads, PWM-DCM at low loads, and PFM-DCM at very low loads. The transition between the different operating modes is seamless.

表 8-1 shows the function table of the MODE/SYNC pin and the FPWMEN bit in the CONTROL1 register, which control the operating mode of the device.

<b>MODE/SYNC Pin</b>	<b>FPWMEN Bit</b>	<b>Operating Mode</b>	<b>Remark</b>
LOW		<b>PSM</b>	Do not use in a stacked configuration.
		<b>FPWM</b>	
High		<b>FPWM</b>	
Sync Clock		<b>FPWM</b>	

表 **8-1. FPWM Mode and Power-Save Mode Selection**

## *8.3.3 Precise Enable*

The Enable (EN) pin is bidirectional and has two functions:

- As an input, EN enables and disables the DC/DC converter in the device.
- As an output, EN provides a SYSTEM\_READY signal to other devices in a stacked configuration.





图 **8-6. Enable Functional Block Diagram**

Because there is an internal open-drain transistor connected to the EN pin, do not drive this pin directly from a low-impedance source. Instead, use a resistor to limit the current flowing into the EN pin (see  $\ddagger$  [10](#page-40-0)).

When power is first applied to the VIN pin, the device pulls the EN pin low until it has loaded the default register settings from nonvolatile memory and read the state of the VSEL, FSEL, and SYNCOUT pins. The device also pulls EN low if a fault, such as thermal shutdown or overvoltage lockout, occurs. In stacked configurations, all devices share a common enable signal, which means that the DC/DC converters in the stack cannot start to switch until *all* devices in the stack have completed the initialization. Similarly, a fault in one or more devices in the stack disables *all* converters in the stack (see  $\frac{4}{10}$  [8.3.17](#page-26-0)).

In standalone (nonstacked) applications, the user can disable the active pulldown of the EN pin if the user sets SINGLE = 1 in the CONTROL3 register. Fault conditions have no effect on the EN pin when SINGLE = 1 (the EN pin is *always* pulled down during device initialization). In stacked applications, make sure that SINGLE = 0.

When the internal SYSTEM READY signal is low (that is, initialization is complete and there are no fault conditions), the internal open-drain transistor is high impedance and the EN pin functions like a standard input. A high level on the EN pin enables the DC/DC converter in the device. A low level disables the DC/DC converter (the I<sup>2</sup>C interface is enabled as soon as the device has completed the initialization and is not affected by the state of the internal ENABLE or SYSTEM\_READY signals).

A low level on the EN pin forces the device into shutdown. During shutdown, the MOSFETs in the power stage are off, the internal control circuitry is disabled, and the device consumes only 20 µA (typical).

The rising threshold voltage of the EN pin is 1.0V and the falling threshold voltage is 0.9 V. The tolerance of the threshold voltages is ±30mV, which means that the user can use the EN pin to implement precise turn-on and turn-off behavior.

When power is applied to the VIN pin, the toggling of the EN pin does not reset the loaded default register settings.

## *8.3.4 Start-Up*

When the voltage on the VIN pin exceeds the positive-going UVLO threshold, the device initializes as follows:

- The device pulls the EN pin low.
- The device enables the internal reference voltage.
- The device reads the state of the VSEL, FSEL, and SYNC\_OUT pins.
- The device loads the default values into the device registers.

When initialization is complete, the device enables  ${}^{12}$ C communication and releases the EN pin. The external circuitry controlling the EN pin now determines the behavior of the device:

- If the EN pin is low, the device is disabled. The user can write to and read from the device registers, but the DC/DC converter does not operate.
- If the EN pin is high, the device is enabled. The user can write to and read from the device registers and, after a short delay, the DC/DC converter starts to ramp up the output.

 $\overline{\otimes}$  [8-7](#page-18-0) shows the start-up sequence when the EN pin is pulled up to V<sub>IN</sub>.

<span id="page-18-0"></span>



图 8-7. Start-Up Timing When EN is Pulled Up to V<sub>IN</sub>

 $\boxtimes$  8-8 shows the start-up sequence when an external signal is connected to the EN pin.





The SSTIME[1:0] bits in the CONTROL2 register select the duration of the soft-start ramp:

- $t_{d(RAMP)} = 500 \mu s$
- $t_{d(RAMP)}$  = 1ms (default)
- $t_{d(RAMP)} = 2ms$
- $t_{d(RAMP)} = 4ms$

The device ignores new values until the soft-start sequence is complete if the user programs the following when the device soft-start sequence has already started:

- A new output voltage setpoint (VOUT[7:0])
- An output voltage range (VRANGE[1:0])
- Soft-start time (SSTIME[1:0]) settings

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If the user change the value of VSET[7:0] during soft start, the device first ramps to the value that VSET[7:0] had when the soft-start sequence began. Then, when soft start is complete, the device ramps up or down to the new value.

The device can start up into a prebiased output. In this case, only a portion of the internal voltage ramp is seen externally (see  $\boxed{8}$  8-9).



## 图 **8-9. Start-Up into a Prebiased Output**

Note that the device *always* operates in DCM during the start-up ramp, regardless of other configuration settings or operating conditions.

## *8.3.5 Switching Frequency Selection*

During device initialization, a resistor-to-digital converter in the device determines the state of the FSEL pin and sets the switching frequency of the DC/DC converter according to  $\frac{1}{\mathcal{R}}$  8-2.





1. For a reliable voltage setting, make sure there is no stray current path connected to the FSEL pin and that the parasitic capacitance between the FSEL pin and GND is less than 100pF.

 $\boxtimes$  8-10 shows a simplified block diagram of the R2D converter used to detect the state of the FSEL pin (an identical circuit detects the state of the VSEL pin – see  $\#$  [8.3.6.2\)](#page-20-0).



## 图 **8-10. FSEL R2D Converter Functional Block Diagram**

<span id="page-20-0"></span>Detection of the state of the FSEL pin works as follows:

To detect the most significant bit (MSB), the circuit opens S1 and S2, and the input buffer detects if a high or a low level is connected to the FSEL pin.

To detect the least significant bit (LSB):

- If the MSB was 0, the circuit closes S1. If the input buffer detects a high level, LSB = 1. If the circuit detects a low level,  $LSB = 0$ .
- If the MSB was 1, the circuit closes S2. If the input buffer detects a low level, LSB = 0. If the circuit detects a high level, LSB = 1.

## *8.3.6 Output Voltage Setting*

## **8.3.6.1 Output Voltage Range**

The device has four different voltage ranges. The VRANGE[1:0] bits in the CONTROL1 register control which range is active (see  $\frac{1}{\sqrt{6}}$  8-3). The default output voltage range after device initialization is 0.4V to 1.675V in 5mV steps.



## 表 **8-3. Voltage Ranges**

Note that every change to the VRANGE[1:0] bits must be followed by a write to the VSET register, even if the value of the VSET[7:0] bits does not change. This sequence is required for the device to start to use the new voltage range.

Also note that the 0.8V to 3.35V range uses a 0.8V reference and the other ranges use a 0.4V reference. Switching to and from the 0.8V to 3.35V range can therefore cause increased output voltage undershoot or overshoot while the device switches the internal reference.

In device variants that do not have  $1^{2}C$ , the output voltage range is factory-set to 0.4V to 1.675V.

## **8.3.6.2 Output Voltage Setpoint**

Together with the selected range, the VSET[7:0] bits in the VSET register control the output voltage setpoint of the device (see  $\bar{\mathcal{R}}$  8-4).





During initialization, the device reads the state of the VSEL pin and selects the default output voltage according to 表 [8-5](#page-21-0). Note that the VSEL pin also selects the I<sup>2</sup>C target address of the device (see 表 [8-10\)](#page-31-0).

<span id="page-21-0"></span>

表 **8-5. Default Output Voltage Setpoints**

(1) For a reliable voltage setting, make sure there is no stray current path connected to the VSEL pin and that the parasitic capacitance between the VSEL pin and GND is less than 100pF.

If the user programs new output voltage setpoint (VOUT[7:0]), output voltage range (VRANGE[1:0]), or soft-start time (SSTIME[1:0]) settings when the device has already begun the soft-start sequence, the device ignores the new values until the soft-start sequence is complete. If the user changes the value of VSET[7:0] during soft start, the device first ramps to the value that VSET[7:0] had when the soft-start sequence began. Then, when soft start is complete, ramps up or down to the new value.

If the user changes VOUT[7:0], VRAMP[1:0], or SSTIME[1:0] while EN is low, the device uses the new values the next time the user enables it.

During start-up, the output voltage ramps up to the target value set by the VSEL pin before ramping up or down to any new value programmed to the device over the I<sup>2</sup>C interface.

## **8.3.6.3 Non-Default Output Voltage Setpoint**

If none of the default voltage range or voltage setpoint combinations are suitable for the application, the user can change these device settings through I<sup>2</sup>C before the user enables the device. Then, when the user pulls the EN pin high, the device starts up with the desired start-up voltage.

Note that if the user changes the device settings through I2C *while the device is ramping*, the device ignores the changes until the ramp is complete.

#### **8.3.6.4 Dynamic Voltage Scaling**

If the user changes the output voltage setpoint while the DC/DC converter is operating, the device ramps up or down to the new voltage setting in a controlled way.

The VRAMP[1:0] bits in the CONTROL1 register sets the slew rate when the device ramps from one voltage to another during DVS (see  $\frac{1}{\mathcal{R}}$  8-6).



#### 表 **8-6. Dynamic Voltage Scaling Slew Rate**

Note that ramping the output to a higher voltage requires additional output current, so that during DVS, the converter must generate a total output current given by:



$$
I_{\text{OUT}} = I_{\text{OUT (DC)}} + C_{\text{OUT}} \frac{dV_{\text{OUT}}}{dt}
$$

(2)

## where

- $\cdot$   $I_{\text{OUT}}$  is the total current the converter must generate while ramping to a higher voltage.
- $I_{\text{OUT(DC)}}$  is the DC load current.
- $C_{\text{OUT}}$  is the total output capacitance.
- $dV_{\text{OUT}}/dt$  is the slew rate of the output voltage (programmable in the range 0.5mV/µs to 10mV/µs).

For correct operation, make sure that the total output current during DVS does not exceed the current limit of the device.

## *8.3.7 Compensation (COMP)*

The COMP pin is the connection point for an external compensation network. A series-connected resistor and capacitor to GOSNS is sufficient for typical applications. The series-connected resistor also provides enough scope to optimize the loop response for a wide range of operating conditions.

When using multiple devices in a stacked configuration, all devices share a common compensation network, and the COMP pin makes sure there is equal current sharing between them (see  $\frac{1}{10}$  [8.3.17](#page-26-0)).

## *8.3.8 Mode Selection and Clock Synchronization (MODE/SYNC)*

A high level on the MODE/SYNC pin selects forced PWM operation. A low level on the MODE/SYNC pin selects power save operation, in which, the device automatically transitions between PWM and PFM, according to the load conditions.

If the user applies a valid clock signal to the MODE/SYNC pin, the device synchronizes the switching cycles to the external clock and automatically selects forced PWM operation.

The MODE/SYNC pin is logically ORed with the FPWMEN bit in the CONTROL1 register (see  $\frac{1}{\sqrt{6}}$  [8-1](#page-16-0)).

When multiple devices are used together in a stacked configuration, the MODE/SYNC pin of the secondary devices is the input for the clock signal (see  $\frac{4}{10}$  [8.3.17\)](#page-26-0).

## *8.3.9 Spread Spectrum Clocking (SSC)*

The device has a spread spectrum clocking function that can reduce electromagnetic interference (EMI). When the SSC function is active, the device modulates the switching frequency to approximately ±10% the nominal value. The frequency modulation has a triangular characteristic (see  $\boxtimes$  8-11).



图 **8-11. Spread Spectrum Clocking Behavior**

To use the SSC function, make sure that:

- SSCEN = 1 in the CONTROL1 register.
- The device is not synchronized to an external clock.



TI recommends to use FPWM operation when using SSC, but SSC is available with PSM operation. To disable the SSC function, make sure that SCCEN = 0 in the CONTROL1 register.

To use the SSC function with multiple devices in a stacked configuration, make sure that the primary converter runs from the internal oscillator and synchronize all secondary converters to the primary clock (see  $\boxed{8}$  [8-14](#page-27-0)).

## *8.3.10 Output Discharge*

The device has an output discharge function that ensures a defined ramp down of the output voltage when the device is disabled and keeps the output voltage close to 0 V while the device is off. The output discharge function is enabled when DISCHEN = 1 in the CONTROL1 register. The output discharge function is enabled by default.

If enabled, the device discharges the output under the following conditions:

- A low level is applied to the EN pin.
- SWEN = 0 in the CONTROL1 register.
- A thermal shutdown event occurs.
- A UVLO event occurs.
- An OVI O event occurs.

The output discharge function is not available until the user has enabled the device at least once after power up. During power down, the device continues to discharge the output for as long as the internal supply voltage is greater than approximately 1.8V.

## *8.3.11 Undervoltage Lockout (UVLO)*

The device has an undervoltage lockout function that disables the device if the supply voltage is too low for correct operation. The negative-going threshold of the UVLO function is 2.5V (typical). If the supply voltage decreases below this value, the device stops switching and, if DISCHEN = 1 in the CONTROL1 register, turns on the output discharge.

## *8.3.12 Overvoltage Lockout (OVLO)*

The device has an overvoltage lockout function that disables the DC/DC converter if the supply voltage is too high for correct operation. The positive-going threshold of the OVLO function is 6.3V (typical). If the supply voltage increases above this value, the device stops switching and, if DISCHEN = 1 in the CONTROL1 register, turns on the output discharge.

The device automatically starts switching again  $-$  it begins a new soft-start sequence  $-$  when the supply voltage falls below 6.2V (typical).

## *8.3.13 Overcurrent Protection*

## **8.3.13.1 Cycle-by-Cycle Current Limiting**

If the peak inductor current increases above the high-side current limit threshold, the device turns off the highside switch and turns on the low-side switch to ramp down the inductor current. The device only turns on the high-side switch again if the inductor current has decreased below the low-side current limit threshold.

Note that because of the propagation delay of the current limit comparator, the current limit threshold in practice can be greater than the DC value specified in the *[Electrical Characteristics](#page-6-0)*. The current limit in practice is given by:

$$
I_L = I_{LIMH} + \Big(\!\frac{V_{IN} - V_{OUT}}{L}\!\Big) t_{pd}
$$

where:

(3)



- $\mathsf{L}$  is the inductor current.
- $I<sub>LIMH</sub>$  is the high-side current limit threshold measured at DC.
- $V_{IN}$  is the input voltage.
- $V_{\text{OUT}}$  is the output voltage.
- L is the effective inductance at the peak current level.
- $\cdot$  t<sub>nd</sub> is the propagation delay of the current limit comparator (typically 5ns).

## **8.3.13.2 Hiccup Mode**

To enable hiccup operation, make sure that HICCUPEN = 1 in the CONTROL1 register.

If hiccup operation is enabled and the high-side switch current exceeds the current limit threshold on 32 consecutive switching cycles, the device:

- Stops switching for 128µs, after which it automatically starts switching again (it starts a new soft-start sequence)
- Sets the HICCUP bit in the STATUS register
- Pulls the PG pin low. The PG pin stays low until the overload condition goes away and the device can start up correctly and regulate the output voltage. Note that power-good function has a deglitch circuit, which delays the rising edge of the power-good signal by 40µs (typical).

Hiccup operation continues in a repeating sequence of 32 cycles in current limit, followed by a pause of 128µs, followed by a soft-start attempt for as long as the output overload condition exists.

The device clears the HICCUP bit if the user reads the STATUS register when the overload condition has been removed.

## **8.3.13.3 Current Limit Mode**

To enable current limit mode, make sure that HICCUPEN = 0 in the CONTROL1 register.

When current limit operation is enabled, the device limits the high-side switch current cycle-by-cycle for as long as the overload condition exists. If the device limits the high-side switch current for four or more consecutive switching cycles, the device sets ILIM = 1 in the STATUS register.

The device clears the ILIM bit if the user reads the STATUS register when the overload condition no longer exits.

## *8.3.14 Power Good (PG)*

The power good (PG) pin is bidirectional and has two functions:

- In a standalone configuration and in the primary device of a stacked configuration, the PG pin is an opendrain output that indicates the status of the converter or stack.
- In a secondary device of a stacked configuration, the PG pin is an input that indicates when the soft-start sequence is complete and all converters in the stack can change from DCM switching to CCM switching.

## **8.3.14.1 Standalone or Primary Device Behavior**

The primary purpose of the PG pin is to indicate if the output voltage is in regulation, but it also indicates if the device is in thermal shutdown or disabled.  $\frac{1}{36}$  8-7 summarizes the behavior of the PG pin in a standalone or primary device.



## 表 **8-7. Power-Good Function Table**





## 表 **8-7. Power-Good Function Table** (续)

 $\boxtimes$  8-12 shows a functional block diagram of the power-good function in a standalone or primary device. A window comparator monitors the output voltage, and the output of the comparator goes high if the output voltage is either less than 95% (typical) or greater than 105% (typical) of the nominal output voltage. The output of the window comparator is deglitched – the typical deglitch time is 40us – and then used to drive the open-drain PG pin.



## 图 **8-12. Power-Good Functional Block Diagram (Standalone or Primary Device)**

During DVS activity, when the DC/DC converter transitions from one output voltage setting to another, the output voltage can temporarily exceed the limits of the window comparator and pull the PG pin low. The device has a feature to disable this behavior. If PGBLNKDVS = 1 in the CONTROL3 register, the device ignores the output of the power-good window comparator while DVS is active.

Note that the PG pin is always low, regardless of the output of the window comparator, when:

- The device is in thermal shutdown.
- The device is disabled.
- The device is in undervoltage lockout.
- The device is in soft start.

## **8.3.14.2 Secondary Device Behavior**

 $\boxtimes$  [8-13](#page-26-0) shows a functional block diagram of the power-good function in a secondary device. During initialization, the device presets FF1 and FF2, which pulls down the PG pin and forces the device to operate in DCM. When the device completes the soft start, it resets FF2, which turns off Q1. However, in a stacked configuration, all

<span id="page-26-0"></span>

devices share the same PG signal, and therefore the PG pin stays low until *all* devices in the stack have completed the soft start. When that happens, FF1 is reset and the converters operate in CCM.



图 **8-13. Power-Good Functional Block Diagram (Secondary Device)**

## *8.3.15 Remote Sense*

The device has two pins, VOSNS and GOSNS, to remotely sense the output voltage. Remote sensing lets the converter sense the output voltage directly at the point-of-load and increases the accuracy of the output voltage regulation.

## *8.3.16 Thermal Warning and Shutdown*

The device has a two-level overtemperature detection function.

If the junction temperature rises above the thermal warning threshold of 150°C (typical), the device sets the TWARN bit in the STATUS register. The device clears the TWARN bit if the user reads the STATUS register when the junction temperature is below the TWARN threshold of 130°C (typical).

If the junction temperature rises above the thermal shutdown threshold of 170°C (typical), the device:

- Stops switching
- Pulls down the EN pin (if SINGLE  $= 0$  in the CONTROL3 register)
- Enables the output discharge (if DISCHEN  $=$  1 in the CONTROL1 register)
- Sets the TSHUT bit in the STATUS register
- Pulls the PG pin low

If the junction temperature falls below the thermal shutdown threshold of 150°C (typical), the device:

- Starts switching again, starting with a new soft-start sequence
- Sets the EN pin to high impedance
- Sets the PG pin to high-impedance

The device clears the TSHUT bit if the user reads the STATUS register when the junction temperature is below the TSHUT threshold of 150°C (typical).

In a stacked configuration, in which all devices share a common enable signal, a thermal shutdown condition in one device disables the entire stack. When the hot device cools down, the whole stack automatically starts switching again.

## *8.3.17 Stacked Operation*

The user can connect multiple devices in parallel in what is known as a "stack"; for example, to increase output current capability or reduce device junction temperature. A stack comprises one *primary* device and one or more *secondary* devices. During initialization, each device monitors the SYNC\_OUT pin to determine if must operate as a primary device or a secondary device:

If there is a 47k Ω resistor between the SYNC\_OUT pin and ground, the device operates as a secondary device.



<span id="page-27-0"></span>• If the SYNC\_OUT pin is high impedance, the device operates as a primary device.

图 8-14 shows the recommended interconnections in a stack of two TPS6287x devices.







The key points to note are:

- All the devices in the stack share a common enable signal, which must be pulled up with a resistance of at least 15kΩ.
- All the devices in the stack share a common power-good signal.
- All the devices in the stack share a common compensation signal.
- All secondary devices must connect a 47k Ω resistor between the SYNC OUT pin and ground.
- The remote sense pins (VOSNS and GOSNS) *of each device* must be connected (do not leave these pins floating).
- Each device must be configured for the same switching frequency.
- The primary device must be configured for forced PWM operation (secondary devices are automatically configured for forced PWM operation).
- A stacked configuration can support synchronization to an external clock or spread-spectrum clocking.
- Only the VSEL pin of the primary device is used to set the default output voltage. The VSEL pin of secondary devices is not used and must be connected to ground.
- The SDA and SCL pins of secondary devices are not used and must be connected to ground.
- A stacked configuration uses a daisy-chained clocking signal, in which each device switches with a phase offset of approximately 140° relative to the adjacent devices in the daisy-chain. To daisy-chain the clocking signal, connect the SYNC OUT pin of the primary device to the MODE/SYNC pin of the first secondary device. Connect the SYNC\_OUT pin of the first secondary device to the MODE/SYNC pin of the second secondary device. Continue this connection scheme for all devices in the stack, to daisy-chain them together.
- Hiccup overcurrent protection must not be used in a stacked configuration.

In a stacked configuration, the common enable signal also acts as a SYSTEM READY signal (see 节 [8.3.3](#page-16-0)). Each device in the stack can pull the EN pin low during device start-up or when a fault occurs. Thus, the stack is only enabled when all devices have completed the start-up sequence and are fault-free. A fault in any one device disables the whole stack for as long as the fault condition exists.

During start-up, the primary converter pulls the COMP pin low for as long as the enable signal (SYSTEM\_READY) is low. When the enable signal goes high, the primary device actively controls the COMP pin and all converters in the stack follow the COMP voltage. During start-up, each device in the stack pulls the PG pin low while it initializes. When initialization is complete, each secondary device in the stack sets the PG pin to a high impedance and the primary device alone controls the state of the PG signal. The PG pin goes high when the stack has completed the start-up ramp and the output voltage is within specification. The secondary converters in the stack detect the rising edge of the power-good signal and switch from DCM operation to CCM operation. After the stack has successfully started up, the primary device controls the power-good signal in the normal way. In a stacked configuration, there are some faults that only affect individual devices, and other faults that affect all devices. For example, if one device enters current limit, only that device is affected. But a thermal shutdown or undervoltage lockout event in one device disables all devices through the shared enable (SYSTEM\_READY) signal.

## **Functionality During Stacked Operation**

Some device features are not available during stacked operation, or are only available in the primary converter.  $\bar{\mathcal{R}}$  8-8 summarizes the available functionality during stacked operation.

<b>Function</b>	<b>Primary Device</b>	<b>Secondary Device</b>	<b>Remark</b>
<b>UVLO</b>	Yes	Yes	Common enable signal
<b>OVLO</b>	Yes	Yes	Common enable signal
OCP - Current Limit	Yes	Yes	Individual
OCP - Hiccup OCP	No	No	Do not use during stacked operation.
<b>Thermal Shutdown</b>	Yes	Yes	Common enable signal

表 **8-8. Functionality During Stacked Operation**



<span id="page-29-0"></span>

## **Fault Handling During Stacked Operation**

In a stacked configuration, there are some faults that only affect individual devices and other faults that affect all devices. For example, if one device enters current limit, only that device is affected. A thermal shutdown or undervoltage lockout event in one device disables all devices through the shared enable (SYSTEM\_READY) signal.  $\overline{\mathcal{R}}$  8-9 summarizes the fault handling of the TPS6287x devices during stacked operation.





## **8.4 Device Functional Modes**

## *8.4.1 Power-On Reset*

The device operates in POR mode when the supply voltage is less than the POR threshold, 1.4V (typical).

In POR mode, no functions are available and the content of the device registers is not valid.

The device leaves POR mode and enters UVLO mode when the supply voltage increases above the POR threshold.

## *8.4.2 Undervoltage Lockout*

The device operates in UVLO mode when the supply voltage is between the POR and UVLO thresholds.

If the device enters UVLO mode from POR mode, no functions are available. If the device enters UVLO mode from standby mode, the output discharge function is available. The content of the device registers is valid in UVLO mode.

The device leaves UVLO mode and enters POR mode when the supply voltage decreases below the POR threshold. The device leaves UVLO mode and enters standby mode when the supply voltage increases above the UVLO threshold.

## *8.4.3 Standby*

The device operates in standby mode when the supply voltage is greater than the UVLO threshold (and the device has completed the initialization) and any of the following conditions is true:

- A low level is applied to the EN pin.
- $SWEN = 0$  in the CONTROL1 register.

<span id="page-30-0"></span>

- The device junction temperature is greater than the thermal shutdown threshold.
- The supply voltage is greater than the OVLO threshold.

The device initializes for 400 µs (typical) after the supply voltage increases above the UVLO threshold voltage following a device power-on reset. If the supply voltage decreases below the UVLO threshold but not below the POR threshold, the device does not reinitialize when the supply voltage increases again. During initialization, the device reads the state of the FSEL, VSEL, and SYNC\_OUT pins.

The following functions are available in standby mode:

- I<sup>2</sup>C interface
- Output discharge
- Power good

The device leaves standby mode and enters UVLO mode when the supply voltage decreases below the UVLO threshold. The device leaves standby mode and enters on mode when all of the following conditions are true:

- A high-level is applied to the EN pin.
- SWEN = 1 in the CONTROL1 register.
- The device junction temperature is below the thermal shutdown threshold.
- The supply voltage is below the OVLO threshold.

## *8.4.4 On*

The device operates in on mode when the supply voltage is greater than the UVLO threshold and all of the following conditions are true:

- A high-level is applied to the EN pin.
- SWEN = 1 in the CONTROL1 register.
- The device junction temperature is below the thermal shutdown threshold.
- The supply voltage is below the OVLO threshold.

All functions are available in on mode.

The device leaves on mode and enters UVLO mode when the supply voltage decreases below the UVLO threshold. The device leaves on mode and enters standby mode when any of the following conditions is true:

- A low level is applied to the EN pin.
- SWEN = 0 in the CONTROL1 register.
- The device junction temperature is greater than the thermal shutdown threshold.
- The supply voltage is greater than the OVLO threshold.

## **8.5 Programming**

## *8.5.1 Serial Interface Description*

<sup>12</sup>C is a 2-wire serial interface developed by Philips Semiconductor, now NXP Semiconductors (see <sup>12</sup>C-Bus Specification and User Manual, Revision 6, 4 April 2014). The bus consists of a data line (SDA) and a clock line (SCL) with pullup structures. When the bus is *idle*, both SDA and SCL lines are pulled high. All I2C-compatible devices connect to the I2C bus through open-drain I/O pins, SDA and SCL. A *controller*, usually a microcontroller or a digital signal processor, controls the bus. The controller is responsible for generating the SCL signal and device addresses. The controller also generates specific conditions that indicate the START and STOP of data transfer. A *target* receives data, transmits data, or both on the bus under control of the controller.

The TPS6287x device operates as a target and supports the following data transfer *modes*, as defined in the <sup>2</sup>C-Bus Specification: standard mode (100 kbps), fast mode (400 kbps), and fast mode plus (1 Mbps). The interface adds flexibility to the power supply solution, enabling most functions to be programmed to new values depending on the instantaneous application requirements. Register contents remain intact as long as the input voltage remains above 1.4V.

The data transfer protocol for standard and fast modes is exactly the same, therefore, they are referred to as F/S-mode in this document. The device supports 7-bit addressing; general call addresses are not supported.

<span id="page-31-0"></span>The state of the VSEL pin during power up defines the I<sup>2</sup>C target address of the device (see  $\bar{\ddot{\mathcal{R}}}$  8-10). Note that the VSEL pin also sets the default start-up voltage of the device (see  $\frac{1}{\mathcal{R}}$  [8-4](#page-20-0)).



## 表 **8-10. I2C Interface Target Address Selection**

(1) Available I<sup>2</sup>C address. This parameter is Device number dependent. Refer to the Device option Table in  $\ddot{\mathbf{\tau}}$ [5](#page-2-0)

TI recommends that the  $12C$  controller initiates a STOP condition on the  $12C$  bus after the initial power up of SDA and SCL pullup voltages to ensure reset of the I<sup>2</sup>C engine.

## *8.5.2 Standard, Fast, Fast Mode Plus Protocol*

The controller initiates a data transfer by generating a start condition. The start condition is when a high-to-low transition occurs on the SDA line while SCL is high, as shown in  $\boxtimes$  8-15. All I<sup>2</sup>C-compatible devices must recognize a start condition.



图 **8-15. START and STOP Conditions**

The controller then generates the SCL pulses, and transmits the 7-bit address and the read and write direction bit R/W on the SDA line. During all transmissions, the controller makes sure that data is valid. A valid data condition requires the SDA line to be stable during the entire high period of the clock pulse (see  $\boxtimes$  8-16). All devices recognize the address sent by the controller and compare the address to the internal fixed addresses. Only the target with a matching address generates an acknowledge (see  $\&$  [8-17](#page-32-0)) by pulling the SDA line low during the entire high period of the ninth SCL cycle. Upon detecting this acknowledge, the controller knows that a communication link with a target has been established.



图 **8-16. Bit Transfer on the Serial Interface**

The controller generates further SCL cycles to either transmit data to the target  $(R/\overline{W})$  bit 0) or receive data from the target (R/W bit 1). In either case, the target must acknowledge the data sent by the controller. So an

<span id="page-32-0"></span>

acknowledge signal can either be generated by the controller or by the target, depending on which one is the receiver. 9-bit valid data sequences consisting of 8-bit data and 1-bit acknowledge can continue as long as necessary.

To signal the end of the data transfer, the controller generates a stop condition by pulling the SDA line from low to high while the SCL line is high (see  $\mathbb{Z}$  [8-15\)](#page-31-0). This stop condition releases the bus and stops the communication link with the addressed target. All <sup>12</sup>C-compatible devices must recognize the stop condition. Upon the receipt of a stop condition, all devices know that the bus is released, and they wait for a start condition followed by a matching address.

Attempting to read data from register addresses not listed in this section will result in 0x00 being read out.









## *8.5.3 I <sup>2</sup>C Update Sequence*

The following are required for a single update:

- A start condition
- A valid  $1^2C$  address
- A register address byte
- A data byte

After the receipt of each byte, the receiving device acknowledges by pulling the SDA line low during the high period of a single clock pulse. A valid I2C address selects the target. The target performs an update on the falling edge of the acknowledge signal that follows the LSB byte.

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## *8.5.4 I <sup>2</sup>C Register Reset*

The  $I^2C$  registers can be reset by:

- Pulling the input voltage below 1.4V (typical).
- Setting the RESET bit in the CONTROL register. When RESET = 1, all registers are reset to the default values and a new start-up begins immediately. After  $t_{d(EN)}$ , the user can program the I<sup>2</sup>C registers again.

<span id="page-34-0"></span>

## **9 Register Map**

表 9-1 lists the device registers. Consider all register offset addresses not listed in 表 9-1 as reserved locations. Do not modify the register contents.



Complex bit access types are encoded to fit into small table cells.  $\frac{1}{6}$  9-2 shows the codes that are used for access types in this section.



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## <span id="page-35-0"></span>**9.1 VSET Register (Address = 0h) [Reset = X]**

VSET is shown in  $\boxed{8}$  9-1 and described in  $\frac{1}{\sqrt{6}}$  9-3.

Return to the [Summary Table.](#page-34-0)

This register controls the output voltage setpoint.





## 表 **9-3. VSET Register Field Descriptions**

English Data Sheet: [SLVSGC5](https://www.ti.com/lit/pdf/SLVSGC5)

<span id="page-36-0"></span>

## **9.2 CONTROL1 Register (Address = 1h) [Reset = 2Ah]**

CONTROL1 is shown in  $\boxed{8}$  9-2 and described in  $\frac{1}{6}$  9-4.

Return to the [Summary Table.](#page-34-0)

This register controls various device configuration options.





## 表 **9-4. CONTROL1 Register Field Descriptions**

## <span id="page-37-0"></span>**9.3 CONTROL2 Register (Address = 2h) [Reset = 9h]**

CONTROL2 is shown in  $\boxed{8}$  9-3 and described in  $\frac{1}{6}$  9-5.

Return to the [Summary Table.](#page-34-0)

This register controls various device configuration options.

#### 图 **9-3. CONTROL2 Register**





## 表 **9-5. CONTROL2 Register Field Descriptions**

<span id="page-38-0"></span>

## **9.4 CONTROL3 Register (Address = 3h) [Reset = 0h]**

CONTROL3 is shown in  $\boxed{8}$  9-4 and described in  $\frac{1}{\sqrt{6}}$  9-6.

Return to the [Summary Table.](#page-34-0)

This register controls various device configuration options.

## 图 **9-4. CONTROL3 Register**





## 表 **9-6. CONTROL3 Register Field Descriptions**



## <span id="page-39-0"></span>**9.5 STATUS Register (Address = 4h) [Reset = 2h]**

STATUS is shown in  $\boxtimes$  9-5 and described in  $\ddot{\textless}$  9-7.

Return to the [Summary Table.](#page-34-0)

This register returns the device status flags.

## 图 **9-5. STATUS Register**



## 表 **9-7. STATUS Register Field Descriptions**



<span id="page-40-0"></span>

## **10 Application and Implementation**

备注

以下应用部分中的信息不属于 TI 器件规格的范围,TI 不担保其准确性和完整性。TI 的客 户应负责确定 器件是否适用于其应用。客户应验证并测试其设计,以确保系统功能。

## **10.1 Application Information**

The following section discusses selection of the external components to complete the power supply design for typical a application.

## **10.2 Typical Application**



图 **10-1. Typical Application Schematic**

## *10.2.1 Design Requirements*

 $\bar{\mathcal{R}}$  10-1 lists the operating parameters for this application example.

Symbol	<b>Parameter</b>	Value
$V_{IN}$	Input voltage	3.3V
V <sub>OUT</sub>	Output voltage	0.75V
<b>TOL</b> <sub>VOUT</sub>	Output voltage tolerance allowed by the application	±3.3%
<b>TOL</b> <sub>DC</sub>	Output voltage tolerance of the TPS6287x (DC accuracy)	±1%
$\Delta$ $I_{\text{OUT}}$	Output current load step	±7.5A
t <sub>t</sub>	Load step transition time	$1 \mu s$
$\mathsf{f}_\mathsf{SW}$	Switching frequency	2.25 MHz
L	Inductance	110 nH
<b>TOL<sub>IND</sub></b>	Inductor tolerance	±20%
$g_m$	Error amplifier transconductance	1.5 <sub>m</sub> S
$\tau$	Internal timing parameter	12.5 $\mu$ s
TOL <sub>T</sub>	Tolerance of the internal timing parameter	$±30\%$

表 **10-1. Design Parameters**

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Product Folder Links: *[TPS62870](https://www.ti.com.cn/product/cn/tps62870?qgpn=tps62870) [TPS62871](https://www.ti.com.cn/product/cn/tps62871?qgpn=tps62871) [TPS62872](https://www.ti.com.cn/product/cn/tps62872?qgpn=tps62872) [TPS62873](https://www.ti.com.cn/product/cn/tps62873?qgpn=tps62873)*

English Data Sheet: [SLVSGC5](https://www.ti.com/lit/pdf/SLVSGC5)







## **Preliminary Calculations**

The maximum allowable deviation of the power supply is ±3.3%. The DC accuracy of the TPS6287x is specified as  $±1%$ , therefore, the maximum output voltage variation during a transient is given by:

$$
\Delta V_{\text{OUT}} = \pm V_{\text{OUT}} \times (3.3\% - 1\%) = \pm 17.25 \text{mV}
$$
\n(4)

## *10.2.2 Detailed Design Procedure*

The following subsections describe how to calculate the external components required to meet the specified transient requirements of a given application. The calculations include the worst-case variation of components and use the RMS method to combine the variation of uncorrelated parameters.

#### **10.2.2.1 Selecting the Inductor**

The TPS6287x devices have been optimized for inductors in the range 50nH to 300nH. If the transient response of the converter is limited by the slew rate of the current in the inductor, using a smaller inductor can improve performance. However, the output ripple current increases as the value of the inductor decreases, and higher output current ripple generates higher output voltage ripple, which adds to the transient overshoot or undershoot. The optimal configuration for a given application is always a trade-off between a number of parameters. TI recommends a starting value of 110nH for typical applications.

The peak-to-peak inductor current ripple is given by:

$$
I_{L(PP)} = \frac{V_{OUT}}{V_{IN}} \left( \frac{V_{IN} - V_{OUT}}{N\phi \times L \times f_{SW}} \right)
$$
(5)

$$
I_{L(PP)} = \frac{0.75}{3.3} \left( \frac{3.3 - 0.75}{1 \times 110 \times 10^{-9} \times 2.25 \times 10^6} \right) = 2.342A
$$
 (6)

表 10-2 lists a number of inductors suitable for use with this application. This list is not exhaustive and other inductors from other manufacturers can also be suitable.



## 表 **10-2. List of Recommended Inductors**

(1) See the *Third-Party Products Disclaimer*.

#### **10.2.2.2 Selecting the Input Capacitors**

As with all buck converters, the input current of the TPS6287x devices is discontinuous. The input capacitors provide a low-impedance energy source for the device, and the value, type, and location are critical for correct



operation. TI recommends low-ESR multilayer ceramic capacitors for best performance. In practice, the total input capacitance is typically comprised of a combination of different capacitors, in which larger capacitors provide the decoupling at lower frequencies and smaller capacitors provide the decoupling at higher frequencies.

The TPS6287x devices feature a *butterfly* layout with two pairs of VIN and GND pins on opposite sides of the package. This allows the input capacitors to be placed symmetrically on the PCB so that the electromagnetic fields generated cancel each other out, thereby reducing EMI.

The duty cycle of the converter is given by:

$$
D = \frac{V_{OUT}}{\eta \times V_{IN}}\tag{7}
$$

where

- $V_{IN}$  is the input voltage.
- $V_{OUT}$  is the output voltage.
- η is the efficiency.

$$
D = \frac{0.75}{0.9 \times 3.3} = 0.253
$$
 (8)

The value of input capacitance needed to meet the input voltage ripple requirements is given by:

$$
C_{IN} = \frac{D \times (1 - D) \times I_{OUT}}{V_{IN}(PP) \times f_{sw}}
$$
(9)

where

- D is the duty cycle.
- $f_{sw}$  is the switching frequency.
- L is the inductance.
- $\cdot$  I<sub>OUT</sub> is the output current.

100mV is used as the input voltage ripple target.

$$
C_{IN} = \frac{0.253 \times (1 - 0.253) \times 11.3}{0.1 \times 2.25 \times 10^6} = 9.5 \mu F
$$
\n(10)

The value of C<sub>IN</sub> calculated with 方程式 9 is the *effective* capacitance after all derating, tolerance, and aging effects have been considered. 5µF effective capacitance per input pin is required. TI recommends multilayer ceramic capacitors with an X7R dielectric (or similar) for  $C_{\text{IN}}$ , and these capacitors must be placed as close to the VIN and GND pins as possible to minimize the loop area.

表 10-3 lists a number of capacitors suitable for this application. This list is not exhaustive and other capacitors from other manufacturers can also be suitable.

表 **10-3. List of Recommended Input Capacitors**

Capacitance	<b>Dimensions</b>	<b>Voltage Rating</b>	Manufacturer, Part Number <sup>(1)</sup>	
	mm (lnch)			
470nF ±10%	1005 (0402)	10V	Murata, GCM155C71A474KE36D	
470nF ±10%	1005 (0402)	10V	TDK, CGA2B3X7S1A474K050BB	
$10 \mu F \pm 10\%$	2012 (0805)	10V	Murata, GCM21BR71A106KE22L	
$10 \mu F \pm 10\%$	2012 (0805)	10V	TDK, CGA4J3X7S1A106K125AB	
$22 \mu F \pm 10\%$	3216 (1206)	10V	Murata, GCM31CR71A226KE02L	
$22 \mu F + 20\%$	3216 (1206)	10V	TDK, CGA5L1X7S1A226M160AC	

(1) See the *Third-Party Products Disclaimer*.

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#### **10.2.2.3 Selecting the Compensation Resistor**

Use 方程式 11 to calculate the recommended value of compensation resistor,  $R_z$ :

$$
R_Z = \frac{1}{g_m} \left( \frac{\pi \times \left( \Delta I_{OUT} + \frac{I_L(PP)}{2} \right) \times \frac{L}{N\Phi}}{4 \times \tau \times \Delta V_{OUT}} - 1 \right) \left( 1 + \sqrt{TOL_{IND}^2 + TOL_{\tau}^2} \right)
$$
(11)

$$
R_Z = \frac{1}{1.5 \times 10^{-3}} \left( \frac{\pi \times (7.5 + \frac{2.342}{2}) \times \frac{110 \times 10^{-9}}{1}}{4 \times 12.5 \times 10^{-6} \times 17.25 \times 10^{-3}} - 1 \right) \left( 1 + \sqrt{20\%^2 + 30\%^2} \right) = 2.244 k\Omega
$$
 (12)

Rounding up, the closest standard value from the E24 series is 2.4k  $\Omega$ .

#### **10.2.2.4 Selecting the Output Capacitors**

In practice, the total output capacitance is typically comprised of a combination of different capacitors, in which larger capacitors provide the load current at lower frequencies and smaller capacitors provide the load current at higher frequencies. The value, type, and location of the output capacitors are critical for correct operation. TI recommends low-ESR multilayer ceramic capacitors with an X7R dielectric (or similar) for best performance.

The TPS6287x devices feature a butterfly layout with two GND pins on opposite sides of the package. This allows the output capacitors to be placed symmetrically on the PCB such that the electromagnetic fields generated cancel each other out, thereby reducing EMI.

The transient response of the converter is limited by one of two criteria:

- The slew rate of the current through the inductor, in which case, the feedback loop of the converter saturates.
- The maximum allowed ratio of converter bandwidth to switching frequency, in which the converter remains in regulation (that is, the loop does not saturate). TI recommends a minimum ratio of four for typical applications.

Which of the above criteria applies in any given application depends on the operating conditions and component values used. Therefore, TI recommends that the user calculate the output capacitance for both cases, and select the higher of the two values.

If the converter remains in regulation, the minimum output required capacitance is given by:

$$
C_{OUT(min)(reg)} = \left(\frac{\tau \times (1 + g_m \times R_Z)}{2 \times \pi \times \frac{L}{N\Phi} \times \frac{f_{SW}}{4}}\right) \left(1 + \sqrt{TOL_T^2 + TOL_{IND}^2 + TOL_{fSW}^2}\right)
$$
(13)

$$
C_{OUT(min)(reg)} = \left(\frac{12.5 \times 10^{-6} \times \left(1 + 1.5 \times 10^{-3} \times 2.4 \times 10^{3}\right)}{2 \times \pi \times \frac{110 \times 10^{-9}}{1} \times \frac{2.25 \times 10^{6}}{4}}\right)\left(1 + \sqrt{30\%^{2} + 20\%^{2} + 10\%^{2}}\right) = 203.2 \mu F\tag{14}
$$

If the converter loop saturates, the minimum output capacitance is given by:

$$
C_{OUT(min)(sat)} = \frac{1}{\Delta V_{OUT}} \left( \frac{\frac{L}{N\Phi} \times \left( \Delta I_{OUT} + \frac{I_{L(PP)}}{2} \right)^2}{2 \times V_{OUT}} - \frac{\Delta I_{OUT} \times t_t}{2} \right) (1 + TOL_{IND}) \tag{15}
$$

$$
C_{OUT(min)(sat)} = \frac{1}{17.25 \times 10^{-3}} \left( \frac{110 \times 10^{-9}}{1} \times \left( 7.5 + \frac{2.342}{2} \right)^2 \right) - \frac{7.5 \times 1 \times 10^{-6}}{2} \right) (1 + 20\%) = 122.7 \mu F
$$
 (16)

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In this case, choose  $C_{\text{OUT(min)}} = 203 \mu F$  as the larger of the two values for the output capacitance.

When calculating worst-case component values, use the value calculated above as the *minimum* output capacitance required. For ceramic capacitors, the *maximum* capacitance when considering tolerance, DC bias, temperature, and aging effects is typically two times the minimum capacitance. In this case, the maximum capacitance  $C_{\text{OUT(max)}}$  is 406  $\mu$  F.





(1) See the *Third-Party Products Disclaimer*.

#### 10.2.2.5 Selecting the Compensation Capacitor, C<sub>C</sub>

First, use 方程式 17 to calculate the bandwidth of the inner loop:

$$
BW_{\text{INNER}} = \frac{\tau}{2\pi \times \frac{L}{N\Phi} \times C_{\text{OUT(max)}}}
$$
(17)

BW<sub>INNER</sub> = 
$$
\frac{12.5 \times 10^{-6}}{2\pi \times \frac{110 \times 10^{-9}}{1} \times 203.2 \times 10^{-6}} = 89 \text{kHz}
$$
 (18)

Next, calculate the product of  $g_mR_z$ :

$$
g_m \times R_Z = 1.5 \times 10^{-3} \times 2.4 \times 10^3 = 3.6
$$
 (19)

If g<sub>m</sub>R<sub>Z</sub> > than 1, use 方程式 20 to calculate the recommended value of C<sub>C</sub>. If g<sub>m</sub>R<sub>Z</sub> < 1, use 方程式 22 to calculate the recommended value of  $C_{C}$ .

$$
C_C = \frac{2}{\pi \times BW_{INNER} \times g_m \times R_Z^2}
$$
 (20)

$$
C_{C} = \frac{2}{\pi \times 89 \times 10^{3} \times 1.5 \times 10^{-3} \times (2.4 \times 10^{3})^{2}} = 0.828 \text{nF}
$$
\n(21)

The closest standard value from the E12 series is 0.82nF.

$$
C_C = \frac{2 \times g_m}{\pi \times BW_{INNER}} \tag{22}
$$

#### 10.2.2.6 Selecting the Compensation Capacitor, C<sub>C2</sub>

The compensation capacitor,  $C_{C2}$ , is an optional capacitor that TI recommends the user include to bypass highfrequency noise away from the COMP pin. The value of this capacitor is not critical; 1pF or 22pF capacitors are suitable for typical applications.



## <span id="page-45-0"></span>*10.2.3 Application Curves*



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## *10.2.3 Application Curves (continued)*





<span id="page-47-0"></span>*10.2.3 Application Curves (continued)*



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## *10.2.3 Application Curves (continued)*





## <span id="page-49-0"></span>**10.3 Best Design Practices**



## **10.4 Power Supply Recommendations**

The TPS6287x family has no special requirements for the input power supply. The output current rating of the input power supply must be rated according to the supply voltage and current requirements of the TPS6287x.

## **10.5 Layout**

## *10.5.1 Layout Guidelines*

Achieving the performance the TPS6287x devices are capable of requires proper PDN and PCB design. TI therefore recommends the user perform a power integrity analysis on the design. There are a number of commercially available power integrity software tools, and the user can use these tools to model the effects on performance of the PCB layout and passive components.

In addition to the use of power integrity tools, TI recommends the following basic principles:

- Place the input capacitors close to the VIN and GND pins. Position the input capacitors in order of increasing size, starting with the smallest capacitors closest to the VIN and GND pins. Use an identical layout for both VIN-GND pin pairs of the package, to gain maximum benefit from the butterfly configuration.
- Place the inductor close to the device and keep the SW node small.
- Connect the exposed thermal pad and the GND pins of the device together. Use multiple thermal vias to connect the exposed thermal pad of the device to one or more ground planes (TI's EVM uses nine 150µm thermal vias).
- Use multiple power and ground planes.
- Route the VOSNS and GOSNS remote sense lines as a differential pair and connect them to the lowestimpedance point of the PDN. If the desired connection point is not the lowest impedance point of the PDN, optimize the PDN until it is. Do not route the VOSNS and GOSNS close to any of the switch nodes.
- Connect the compensation components between VOSNS and GOSNS. Do not connect the compensation components directly to power ground.
- Use multiple vias to connect each capacitor pad to the power and ground planes (TI's EVM typically uses four vias per pad).
- Use plenty of stitching vias to make sure of a low impedance connection between different power and ground planes.
- Make sure that the capacitance located at the load is at least twice the amount of the capacitance located at the device.



## *10.5.2 Layout Example*

图 10-25 shows the top layer of one of the evaluation modules for this device. It demonstrates the practical implementation of the PCB layout principles previously listed. The user can find a complete set drawings of all the layers used in this PCB in the evaluation module's user guide.





## <span id="page-51-0"></span>**11 Device and Documentation Support**

## **11.1 Device Support**

## *11.1.1* 第三方产品免责声明

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## **11.3** 支持资源

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ESD 的损坏小至导致微小的性能降级,大至整个器件故障。精密的集成电路可能更容易受到损坏,这是因为非常细微的参 数更改都可能会导致器件与其发布的规格不相符。

## **11.6** 术语表

TI [术语表](https://www.ti.com/lit/pdf/SLYZ022) 本术语表列出并解释了术语、首字母缩略词和定义。

<span id="page-52-0"></span>

## **12 Revision History**

注:以前版本的页码可能与当前版本的页码不同





## **13 Mechanical, Packaging, and Orderable Information**

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



## **PACKAGING INFORMATION**



**(1)** The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

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Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

**(3)** MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



# **PACKAGE OPTION ADDENDUM**

**(4)** There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

**(5)** Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### **OTHER QUALIFIED VERSIONS OF TPS62870, TPS62871, TPS62872, TPS62873 :**

• Automotive : [TPS62870-Q1](http://focus.ti.com/docs/prod/folders/print/tps62870-q1.html), [TPS62871-Q1,](http://focus.ti.com/docs/prod/folders/print/tps62871-q1.html) [TPS62872-Q1,](http://focus.ti.com/docs/prod/folders/print/tps62872-q1.html) [TPS62873-Q1](http://focus.ti.com/docs/prod/folders/print/tps62873-q1.html)

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

**TEXAS** 

## **TAPE AND REEL INFORMATION**

**ISTRUMENTS** 





#### **QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**







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# **PACKAGE MATERIALS INFORMATION**

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# **RXS0016A**

# **PACKAGE OUTLINE**

## **VQFN-FCRLF - 1.05 mm max height**

PLASTIC QUAD FLAT PACK- NO LEAD



- per ASME Y14.5M.<br>This drawing is subject to change without notice.
- 
- 



# **EXAMPLE BOARD LAYOUT**

# **RXS0016A VQFN-FCRLF - 1.05 mm max height**

PLASTIC QUAD FLAT PACK- NO LEAD



NOTES: (continued)

- 
- on this view. It is recommended that vias under paste be filled, plugged or tented.



# **EXAMPLE STENCIL DESIGN**

# **RXS0016A VQFN-FCRLF - 1.05 mm max height**

PLASTIC QUAD FLAT PACK- NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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